

PC123XxYSZ1B Series

DIP 4pin Reinforced Insulation Type Photocoupler



■ Description

PC123XxYSZ1B Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option. Input-output isolation voltage(rms) is 5kV. CTR is 50% to 400% (at I_F =5mA, V_{CE} =5V,Ta=25°C)

■ Features

- 1. 4-pin DIP package
- Double transfer mold package (Ideal for Flow Soldering)
- 3. Current transfer ratio

(CTR : MIN. 50% at I_F =5 mA, V_{CE} =5V, Ta=25°C)

- 4. Several CTR ranks available
- 5.Reinforced insulation type

(Isolation distance: MIN. 0.4mm)

6.Long creepage distance type

(wide lead-form type only: MIN. 8mm)

7. High isolation voltage between input and output

 $(V_{iso}(rms):5kV)$

8.RoHS directive compliant

Agency approvals/Compliance

- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC123)
- 2. Approved by BSI, BS-EN62368 (as model No. **PC123**)
- 3. Approved by SEMKO, EN60065, EN60335-1, EN60950 (as model No. **PC123**)
- 4. Approved by DEMKO, EN60065, EN60335-1,EN60950, (as model No. **PC123**)
- 5. Approved by NEMKO, EN60065, EN60335-1, EN60950 (as model No. **PC123**)
- Approved by FIMKO, EN60065, EN60335-1, EN60950, (as model No. PC123)
- 7.Recognized by CSA file No. CA95323 (as model No. **PC123**)
- Approved by VDE, DIN EN60747-5-5(*) (as an option)
 File No. 40008087 (as model No. PC123)
- 9. Package resin: UL flammability grade (94V 0)

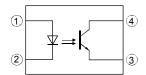
(*) DIN EN60747-5-5: successor standard of DIN VDE0884.

Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- Signal transmission between circuits of different potentials and impedances
- 4. Over voltage detection



■ Internal Connection Diagram

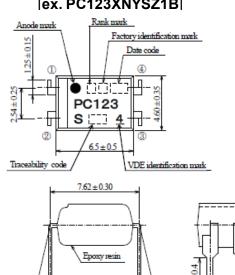


- 1) Anode
- ② Cathode
- ③ Emitter
- (4) Collector

■ Outline Dimensions

(Unit:mm)

1 . Through-Hole [ex. PC123XNYSZ1B]



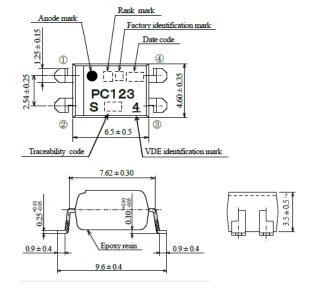
32±04 35±05 4.15±04

Product mass: approx.0.23g

θ: 0~13°

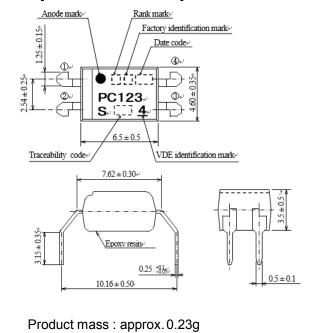
0.25 +01

2 . SMT Gullwing Lead-Form [ex. PC123XNYIP1B]

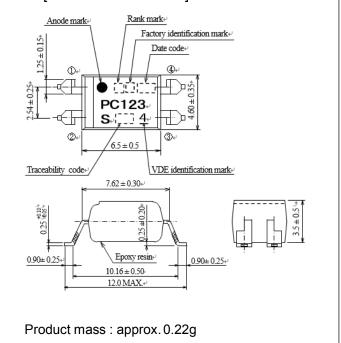


Product mass: approx. 0.22g

3 . Wide Through-Hole Lead-Form [ex. PC123XNYFZ1B]



4 . Wide SMT Gullwing Lead-Form [ex. PC123XNYUP1B]





Date code indication (Ex.)

3-digit number shall be marked the age indication of 1-digit number, and week code of 2-digit number. Week code "01" indicate the week including the first Thursday of January. And later, Monday is the starting point.

Year Week	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
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Date code	MON	TUE	WED	THU	FRI	SAT	SUN
652	12/26	12/27	12/28	12/29	12/30	12/31	1/1
701	1/2	1/3	1/4	1/5	1/6	1/7	1/8
702	1/9	1/10	1/11	1/12	1/13	1/14	1/15
703	1/16	1/17	1/18	1/19	1/20	1/21	1/22
		•			-	•	
	•	•	•	•	•	•	
	•	•	•				•
752	12/11	12/12	12/13	12/14	12/15	12/16	12/17
751	12/18	12/19	12/20	12/21	12/22	12/23	12/24
752	12/25	12/26	12/27	12/28	12/29	12/30	12/31
801	1/1	1/2	1/3	1/4	1/5	1/6	1/7

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material	
K	Japan	SnBi (Bi : 1∼4%)	

Rank mark

Refer to the Model Line-up table.



■ Absolute Maximum Ratings

 $(T_a=25^{\circ}C)$

	Parameter	Symbol	Rating	Unit
	Forward current	I_F	50	mA
I4	*1 Peak forward current	I_{FM}	1	A
Input	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
	Collector-emitter voltage	V _{CEO}	80	V
Output	Emitter-collector voltage	V _{ECO}	6	V
Output	Collector current	$I_{\rm C}$	50	mA
	Collector power dissipation	P _C	150	mW
Total p	power dissipation	P _{tot}	200	mW
*2 Isolatio	on voltage	V _{iso} (rms)	5	kV
Operat	ting temperature	Topr	-30 to +100	\mathbb{C}
Storag	e temperature	T _{stg}	-55 to +125	\mathbb{C}
*2 Solder	ing temperature	T _{sol}	270	$^{\circ}$

^{*1} Pulse width ≤ 100µs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute *3 For 10s

■ Electro-optical Characteristics

(Ta=25°C)

Parameter			Symbol	Condition	MIN.	TYP.	MAX.	Unit
	Forward voltage		V_{F}	I _F =20mA	_	1.2	1.4	V
Input	Reverse current		I_R	V _R =4V	_	_	10	μΑ
	Terminal capacitance		C_t	V=0, f=1kHz	_	30	250	pF
	Dark current		I_{CEO}	$V_{CE} = 50V, I_{F} = 0$	_	_	100	nA
Output	Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	80	_	_	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	_	V
	Collector current		I_{C}	$I_F=5mA, V_{CE}=5V$	2.5	_	20	mA
	Collector-emitter saturation voltage		V _{CE(sat)}	$I_F=20mA, I_C=1mA$	_	0.1	0.2	V
Transfer	Transfer Isolation resistance charac Floating capacitance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
charac-			C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
teristics	Cut-off frequency		f_C	$V_{CE}=5V, I_{C}=2mA, R_{L}=100\Omega, -3dB$	_	80	_	kHz
	Response time Rise time	Risetime	t _r	$V_{CE}=2V$, $I_{C}=2mA$, $R_{L}=100\Omega$	_	4	18	μs
	response unit	Falltime	$t_{\rm f}$	v CE-2 v , IC-2IIIA, KL=10052	_	3	18	μs



■ Model Line-up

Lead Form	Through-Hole		I _C [mA]
	Sleeve	Rank mark	(I _F =5mA,
Daaltana	100pcs/sleeve		V _{CE} =5V,
Package	'		T _a =25°C)
	PC123XNYSZ1B	with or " _ "	2.5 ~ 20
	PC123X1YSZ1B	L	2.5 ~ 7.5
Model No.	PC123X2YSZ1B	M	5.0 ~ 12.5
	PC123X5YSZ1B	N	10 ~ 20
	PC123X8YSZ1B	E	5.0 ~ 10
		'	1
Lead Form	Wide Through-Hole		I _C [mA]
	Sleeve	Rank mark	(I _F =5mA, V _{CF} =5V,
Package	100pcs/sleeve		T _a =25°C)
	PC123XNYFZ1B	with or " _ "	2.5 ~ 20
	PC123X1YFZ1B	L	2.5 ~ 7.5
Model No.	PC123X2YFZ1B	M	5.0 ~ 12.5
	PC123X5YFZ1B	N	10 ~ 20
	PC123X8YFZ1B	Е	5.0 ~ 10
'		'	
Lead Form	SMT Gullwing		I _C [mA]
	Taping	Rank mark	(I _F =5mA,
Package	2,000pcs/reel		$V_{CE}=5V$, $T_a=25^{\circ}C$)
	PC123XNYIP1B	with or " _ "	2.5 ~ 20
	PC123X1YIP1B	L	2.5 ~ 7.5
Model No.	PC123X2YIP1B	M	5.0 ~ 12.5
		***	12.0

Lead Form	Wide SMT Gullwing Taping	Rank mark	$I_{C}[mA]$ $(I_{F}=5mA, V_{CF}=5V, I_{C}$
Package	2,000pcs/reel	0pcs/reel	
	PC123XNYUP1B	with or " _ "	2.5 ~ 20
	PC123X1YUP1B	L	2.5 ~ 7.5
Model No.	PC123X2YUP1B	M	5.0 ~ 12.5
	PC123X5YUP1B	N	10 ~ 20
	PC123X8YUP1B	E	5.0 ~ 10

N

Ε

10 ~ 20

5.0 ~ 10

PC123X5YIP1B

PC123X8YIP1B

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

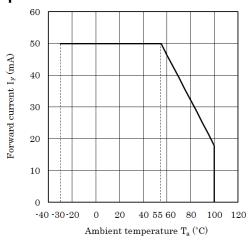


Fig.3 Collector Power Dissipation vs.
Ambient Temperature

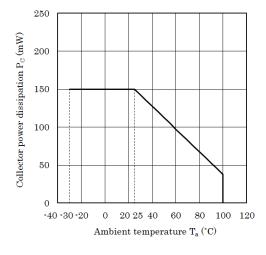


Fig.5 Peak Forward Current vs. Duty Ratio

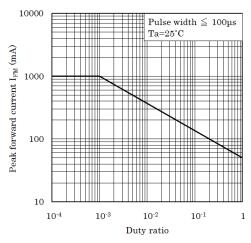


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

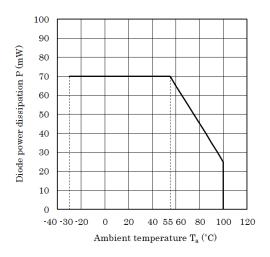


Fig.4 Total Power Dissipation vs. Ambient Temperature

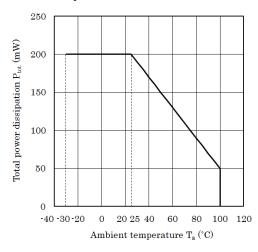


Fig.6 Forward Current vs. Forward Voltage

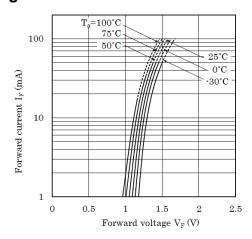




Fig.7 Current Transfer Ratio vs. Forward Current

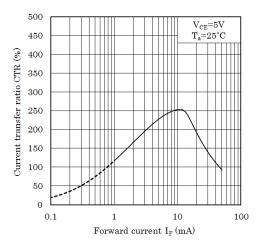


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

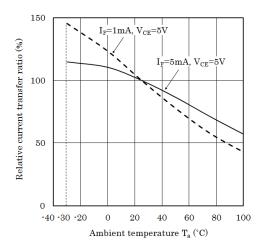


Fig.11 Collector Dark Current vs.

Ambient Temperature

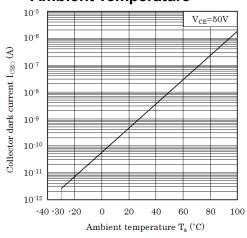


Fig.8 Collector Current vs.
Collector-emitter Voltage

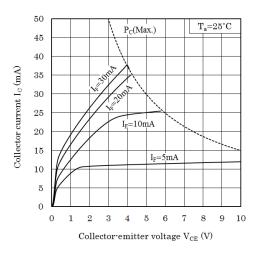


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

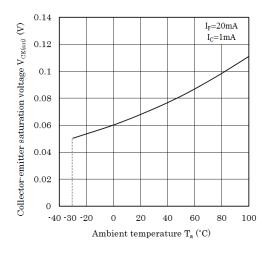


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current

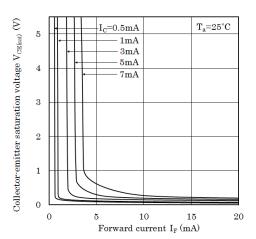




Fig.13 Response Time vs. Load Resistance

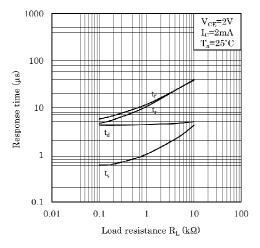


Fig.15 Frequency Response

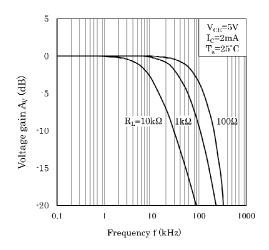


Fig.14 Test Circuit for Response Time

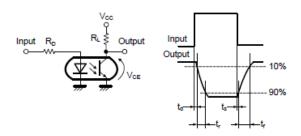
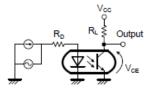


Fig.16 Test Circuit for Frequency Response



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

• Design guide

While operating at I_F (1mA, CTR variation may increase.

Please make design considering this fact.

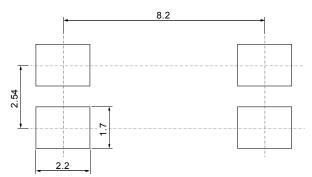
This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

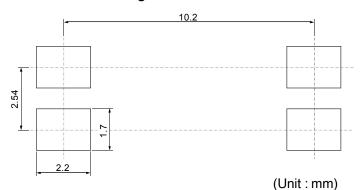
In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

• Recommended foot print (reference)

SMT Gullwing lead-form



Wide SMT Gullwing lead-form



[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

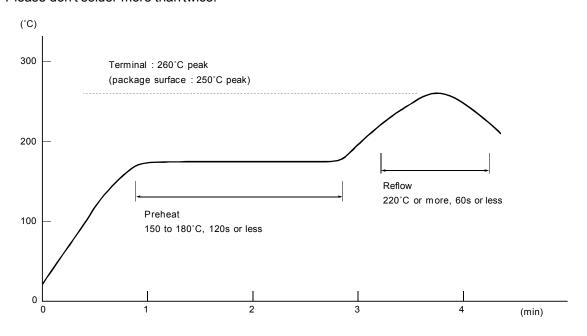
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

• Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

- The RoHS directive(2011/65/EU)
 This product complies with the RoHS directive(2011/65/EU)
 Object substances: mercury, lead, cadmium, hexavalent chromium, polybrominated biphenyls
 (PBB) and polybrominated diphenyl ethers (PBDE)
- (2) Content of six substances specified in Management Methods for Control of Pollution Caused by Electronic Information Products Regulation (Chinese: 电子信息产品污染控制管理办法).

Marking Styles for the Names and Contents of the Hazardous Substances

	Hazardous Substances						
Category	Lead (Pb)	Mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr ⁶⁺)	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)	
Photocoupler	0	0	0	0	0	0	

This table is prepared in accordance with the provisions of SJ/T 11364.

^{• :} Indicates that said hazardous substance contained in all of the homogeneous materials for this part is below the limit requirement of GB/T 26572.



■ Package specification

• Sleeve package

1. Through-Hole, Wide Through-Hole

Package materials

Sleeve: HIPS/PS or PC (with anti-static material)

Stopper: EPM

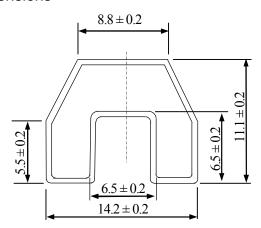
Package method

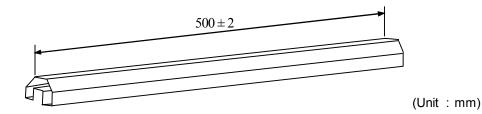
MAX. 100pcs. of products shall be packaged in a sleeve and both of sleeve edges shall be fixed by stoppers.

MAX. 25 sleeves (Product: 2,500pcs.) above shall be packaged in inner case and sealed by tape.

Max 2 bags(product: 5,000pcs) above shall be packaged in packing case, and put a cushioning material inside.

Sleeve outline dimensions







• Tape and Reel package

1. SMT Gullwing

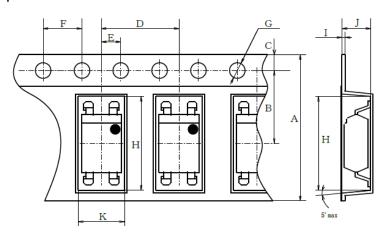
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

Reel: PS

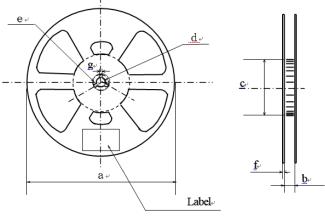
Carrier tape structure and Dimensions



Dimensions List (Unit: mm)

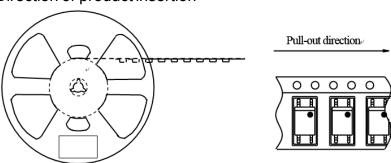
A	В	С	D	Е	F	G
16.0±0.3	7.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0±0.1	4.0 ^{±0.1}	φ1.5 ^{+0.1} _{-0.0}
Н	I	J	K			
10.3 ^{±0.1}	$0.40^{\pm0.05}$	$4.0^{\pm0.1}$	5.3 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(U	nit: mm)
a	b	с	d
ф330	17.5±1.5	φ100±1	ф13.0 ^{±0.5}
e	f	g	
φ21.0±1	2.0±0.5	2.0±0.5	

Direction of product insertion



[Packing: 2,000pcs/reel]



2. Wide SMT Gullwing

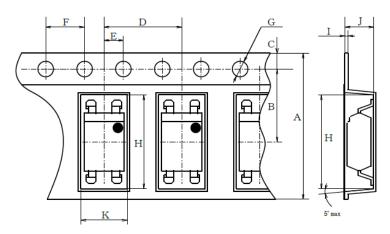
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

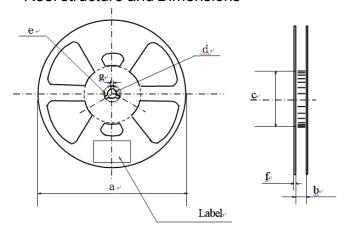
Reel: PS

Carrier tape structure and Dimensions



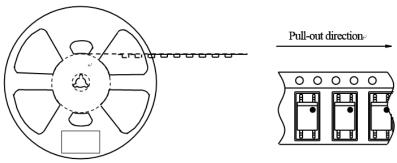
_	Dimensior	(L	Jnit: mm)				
•	A	В	С	D	Е	F	G
	24.0±0.3	11.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0 ^{±0.1}	$4.0^{\pm0.1}$	φ1.5 ^{+0.1} _{-0.0}
	Н	I	J	K			
•	12.5±0.1	$0.40^{\pm0.05}$	4.05 ^{±0.1}	5.3 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
ф330	25.5 ^{±1.5}	$\phi 100^{\pm 1}$	\$\phi13.0\pmu0.5	
e	f	g		
$\phi 23^{\pm 1}$	2.0±0.5	$2.0^{\pm0.5}$		

Direction of product insertion



[Packing: 2,000pcs/reel]